



PJQ5882A

100V Dual N-Channel Enhancement Mode Mosfet

Voltage

100 V

Current

6.5 A

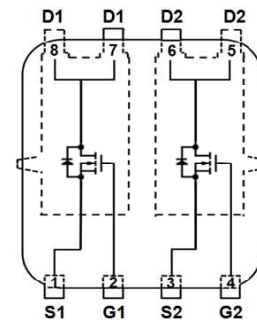
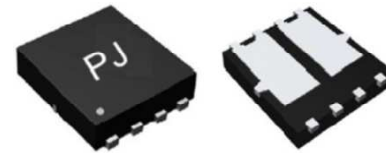
Features

- $R_{DS(ON)}$, $V_{GS}@10V, I_D@3A < 310m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V, I_D@2A < 320m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060B-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0035 ounces, 0.092 grams

DFN5060B-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	100	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ^(Note 4)	$T_C=25^\circ\text{C}$	I_D	6.5	A
	$T_C=100^\circ\text{C}$		4.1	
	$T_A=25^\circ\text{C}$		1.7	
	$T_A=70^\circ\text{C}$		1.3	
Pulsed Drain Current ^(Note 1)	$T_A=25^\circ\text{C}$	I_{DM}	7	
Power Dissipation	$T_C=25^\circ\text{C}$	P_D	31	W
	$T_C=100^\circ\text{C}$		12	
	$T_A=25^\circ\text{C}$		2.1	
	$T_A=70^\circ\text{C}$		1.3	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^\circ\text{C}$
Typical Thermal Resistance ^(Note 5)	Junction to Case	$R_{\theta JC}$	4	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	60	



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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	100	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1	2	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =3A	-	285	310	mΩ
		V _{GS} =4.5V, I _D =2A	-	290	320	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =80V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 6)						
Total Gate Charge	Q _g	V _{DS} =50V, I _D =2.2A, V _{GS} =10V (Note 2,3)	-	8.5	-	nC
Gate-Source Charge	Q _{gs}		-	1.7	-	
Gate-Drain Charge	Q _{gd}		-	1.6	-	
Input Capacitance	C _{iss}	V _{DS} =30V, V _{GS} =0V, f=1.0MHZ (Note 2,3)	-	444	-	pF
Output Capacitance	C _{oss}		-	22	-	
Reverse Transfer Capacitance	C _{rss}		-	10	-	
Gate resistance	R _g	f=1.0MHZ	-	1.3	-	Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} =50V, I _D =2.2A, V _{GS} =10V, R _G =3Ω (Note 2,3)	-	6	-	ns
Turn-On Rise Time	t _r		-	22	-	
Turn-Off Delay Time	t _{d(off)}		-	21	-	
Turn-Off Fall Time	t _f		-	21	-	
Drain-Source Diode						
Diode Forward Current	I _S	---	-	-	6.5	A
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.78	1.2	V
Reverse Recovery Time	T _{rr}	V _{GS} =0V, I _S =2.2A	-	40	-	ns
Reverse Recovery Charge	Q _{rr}	di _S /dt=100A/us (Note 2,3)	-	20	-	nC

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J=25°C.
4. The maximum current rating is package limited.
5. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

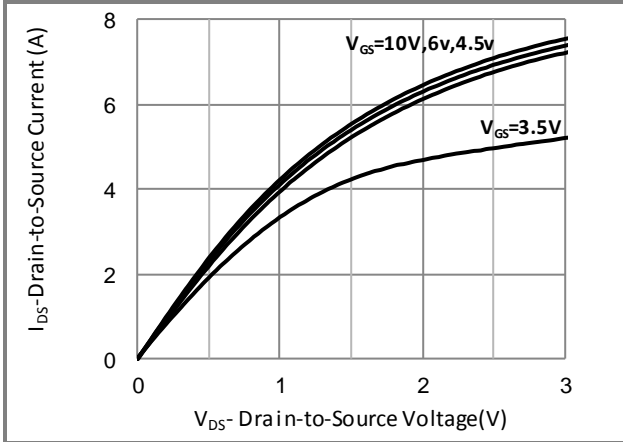


Fig.1 Output Characteristics

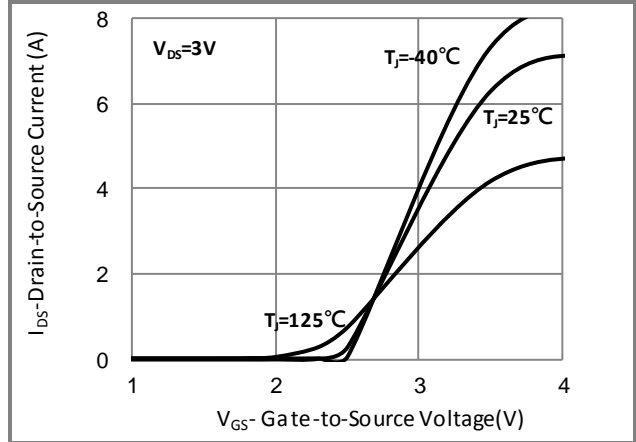


Fig.2 Transfer Characteristics

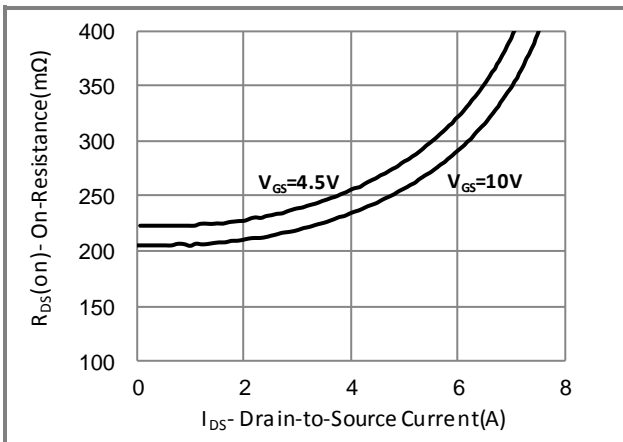


Fig.3 On-Resistance vs. Drain Current

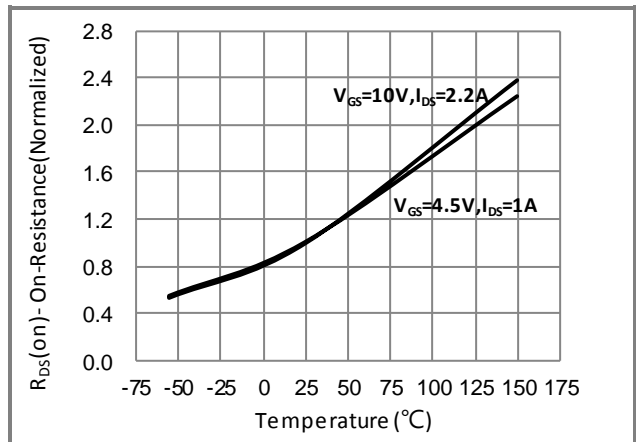


Fig.4 On-Resistance vs. Junction temperature

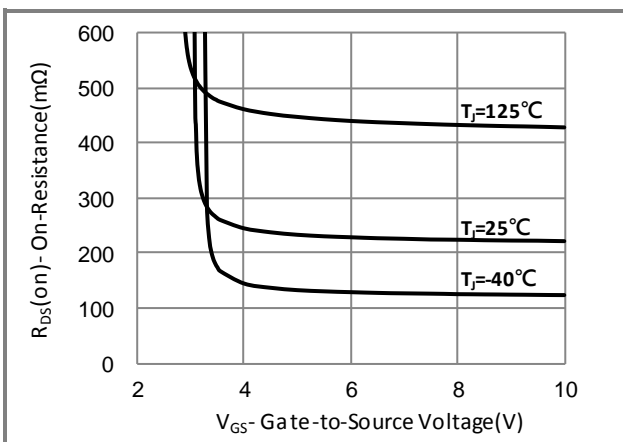


Fig.5 On-Resistance Variation with V_{GS}

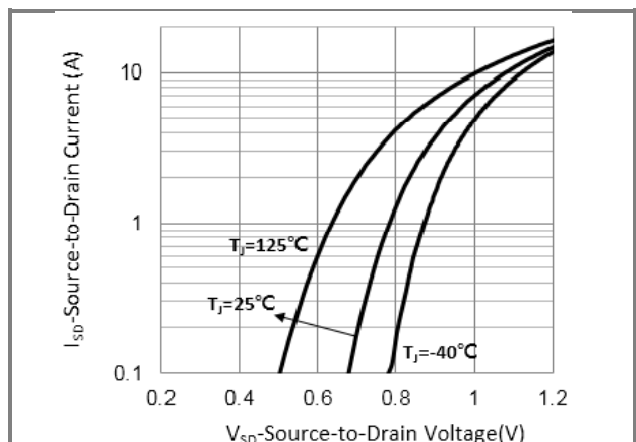


Fig.6 Source-Drain Diode Forward Voltage



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TYPICAL CHARACTERISTIC CURVES

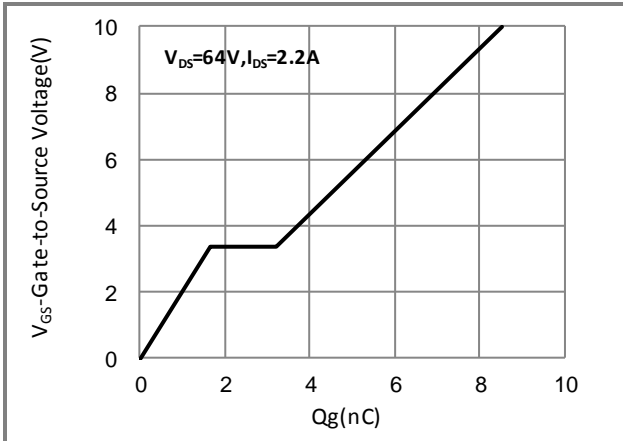


Fig.7 Gate-Charge Characteristics

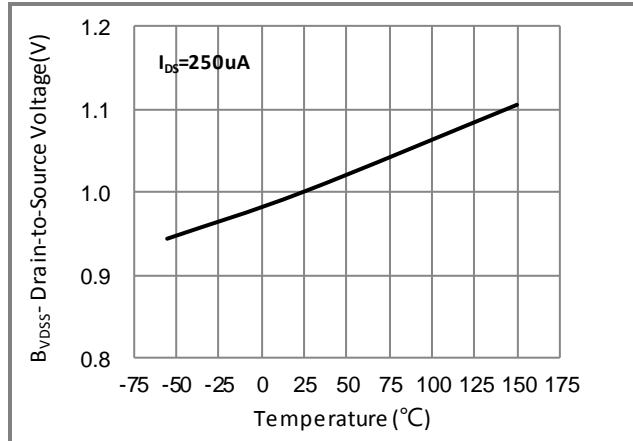


Fig.8 Breakdown Voltage Variation vs. Temperature

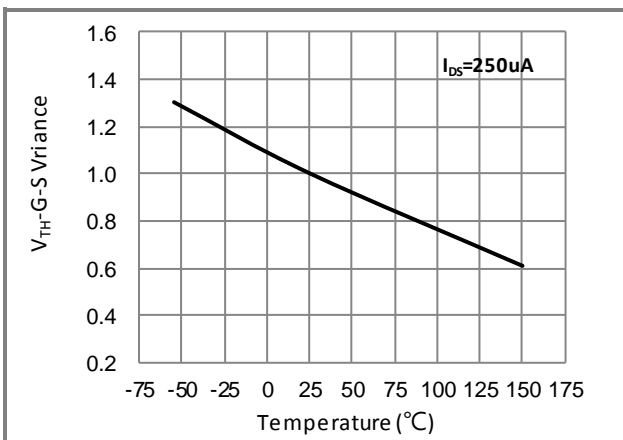


Fig.9 Threshold Voltage Variation with Temperature

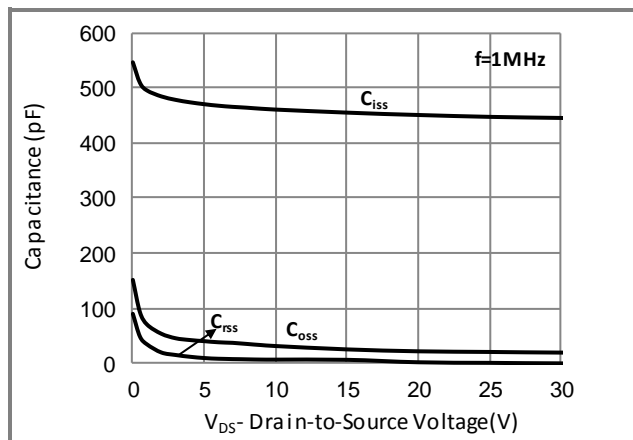


Fig.10 Capacitance vs. Drain-Source Voltage

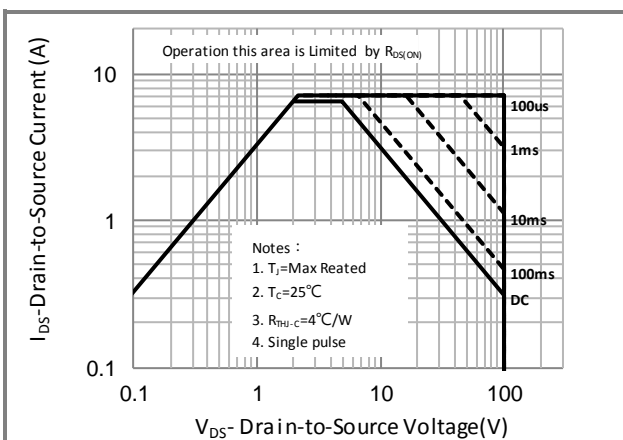


Fig.11 Maximum Safe Operating Area

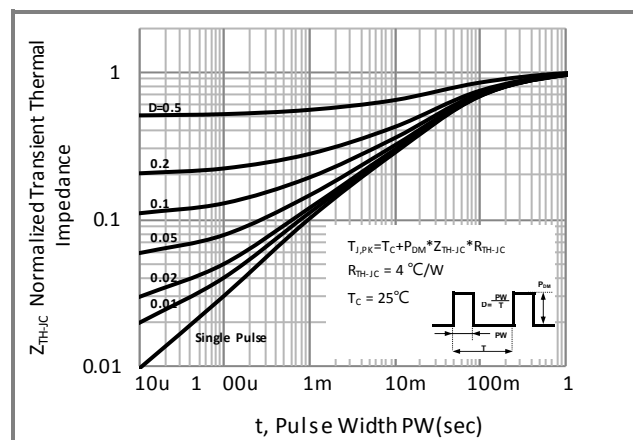


Fig.12 Normalized Transient Thermal Impedance

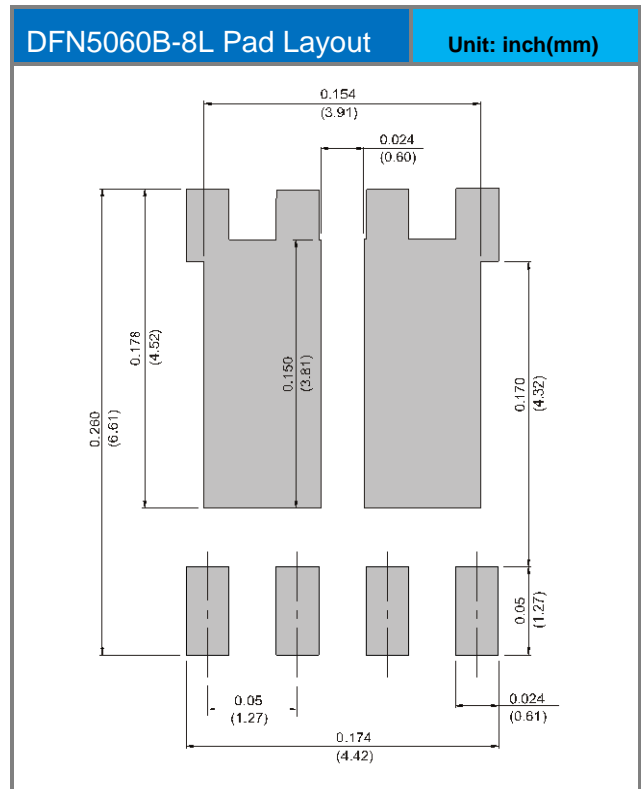
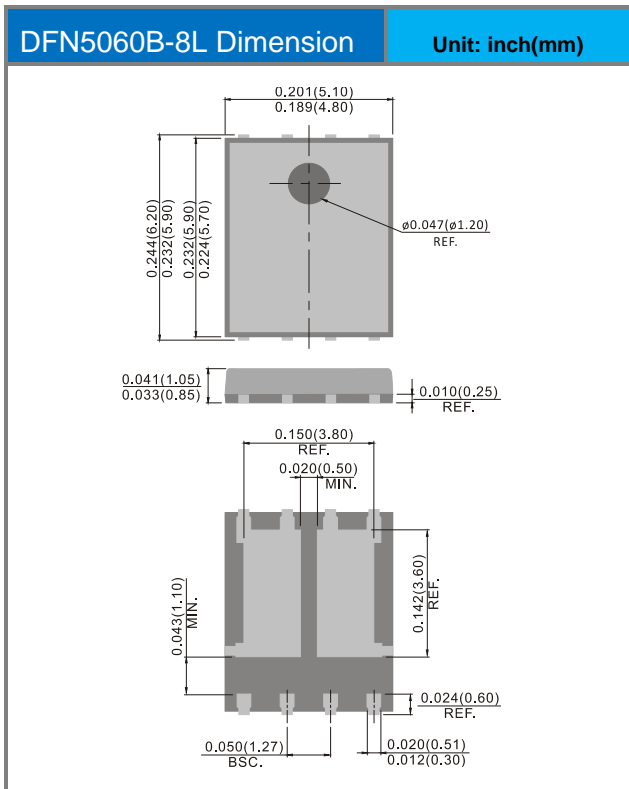


PJQ5882A

Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ5882A_R2_00001	DFN5060B-8L	3000pcs / 13" reel	Q5882A	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





PJQ5882A

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